

Photo Transistor --ORT-PT2142H2

1. Scope:

- This specification applies to NPN Photo Transistor.

2. Structure:

- Top Side : aluminium alloy
- Bottom Side : silver alloy
- Passivation : Silicon Nitride

3. Size:

- Die Size : $508\mu\text{m}\times 1016\mu\text{m}\pm 30\mu\text{m}$
- Thickness : $220\mu\text{m}\pm 30\mu\text{m}$
- Pad Size :
- Base : $60\mu\text{m}\times 60\mu\text{m}\pm 20\mu\text{m}$
- Emitter : $\Phi 160\mu\text{m}\pm 20\mu\text{m}$
- Active Area : $382\mu\text{m}\times 382\mu\text{m}\pm 20\mu\text{m}$
- Pattern Drawing: fig.1.

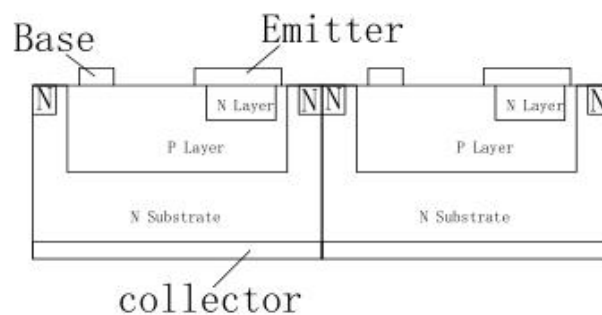
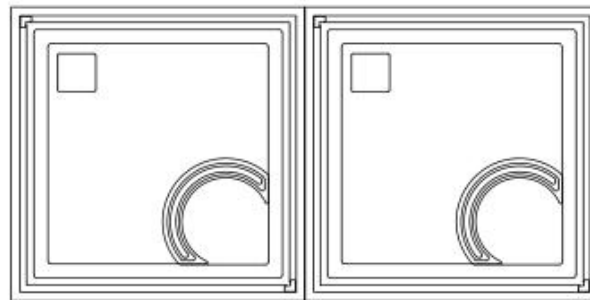


fig.1



4. Electro-Optical Characteristics:

(Ta=+25°C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
C-E Leakage Current	I_{CEO}	$V_{CE}=20V$ $H=0mw/cm^2$			100	nA
C-E Saturation Voltage	V_{CES}	$I_C=5mA$, $I_B=1mA$			250	mV
C-E Voltage	BV_{CEO}	$I_{CE}=500\mu A$	70			V
E-C Voltage	BV_{ECO}	$I_{EC}=50\mu A$	6			V
DC Current Gain	h_{FE}	$V_{CE}=10V$, $I_C=1mA$	300			-

***Note** : BV_{ECO} : h_{FE} : 1000~ (BV_{ECO} = Min. 3V)

5. h_{FE} Classification:

T21423 series(1:1.3)

Classification	T2142-3A	T2142-3B	T2142-3C	T2142-3D	T2142-3E
h_{FE}	600~780	660~860	720~940	780~1020	840~1100

Classification	T2142-3F	T2142-3G	T2142-3H	T2142-3I	T2142-3J
h_{FE}	900~1180	960~1260	1020~1340	1080~1420	1140~1500

Classification	T2142-3K	T2142-3L	T2142-3M	T2142-3N
h_{FE}	1200~1580	1500~2000	2000~2600	2400~3000

T21425 series(1:1.5)

Classification	T2142-5A	T2142-5B	T2142-5C	T2142-5D	T2142-5E
h_{FE}	600-900	700-1050	800-1300	900-1400	1100-1700

Classification	T2142-5F	T2142-5G	T2142-5H
h_{FE}	1300-2000	1500-2300	2000-3000

T21427 series(1:1.7)

Classification	T2142-7A	T2142-7B	T2142-7C	T2142-7D	T2142-7E
h_{FE}	600~1020	680~1160	760-1300	840-1440	920-1580

Classification	T2142-7F	T2142-7G	T2142-7H
h_{FE}	1000-1700	1200-2000	1800-3000

T2142A series(1:2)

Classification	T2142-AA	T2142-AB	T2142-AC	T2142-AD	T2142-AE	T2142-AO
h_{FE}	600~1200	800~1600	1000~2000	1200~2400	2000~3000	600~3000

6. Packing :

- Packing: Sheet Type

7. Application Notes:

- All data are measured by Orient's tester on bare chips within 98% of the nominal value.